

Fast vertical mode expansion method for the simulation of extraordinary terahertz field enhancement in an annular nanogap

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This paper is concerned with electromagnetic wave scattering of an annular nanogap in the terahertz regime. We present an efficient vertical mode expansion method (VMEM) to solve the scattering problem, and study the extraordinary optical transmission and field enhancement for the nanostructure with various configurations. The vertical mode expansion method expands the electromagnetic field in and outside the nanogap along the invariant direction by the one-dimensional modes, where the expansion coefficients satisfy scalar two-dimensional Helmholtz equations on the cross-sectional plane. The continuity conditions of electromagnetic fields on the vertical boundaries of neighboring regions are then employed to establish the linear system for the unknown coefficients. Based on the numerical simulations, we investigate the field enhancement in the nanogap. In particular, we investigate the nanostructure with a series of gap sizes and push the gap width limit to 1 nm in the numerical simulation. Both the normal and oblique incidence cases, the transverse electric (TE) and the transverse magnetic (TM) polarizations cases are considered. © 2017 Optical Society of America

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1. INTRODUCTION

Motivated by significant applications in sensing, spectroscopy and nano-optics, the effect of extraordinary optical transmission through subwavelength apertures has been investigated extensively since Ebbesen's seminal paper [1]. Various subwavelength structures have been developed to achieve strongly confined electromagnetic field near the apertures. These include metallic films perforated with periodic arrays of subwavelength holes or slits, single nano-sized hole or slit, etc. We refer the readers to the review papers [2, 3] and references therein for detailed discussions.

In this paper, we numerically study the enhancement of terahertz (THz) wave inside a single annular nanometer-wide gap that is perforated in a gold film. The terahertz frequency domain is an emerging technological frontier with many potential applications in sensing, spectroscopy, and materials characterization [4, 5]. New techniques have been developed to confine and manipulate terahertz waves using metallic nanostructures (see,

for example, [6–8]). Previously, researchers have shown that there are extraordinary optical transmission and enormously enhanced electric field for small annular gaps, and the field enhancement intensity in the gap keeps increasing with a decreasing gap width [9–14]. Theoretical and experimental studies of the plasmon dispersion in annular gaps have also been reported in [15–18]. Here we present numerical simulations for such extraordinary optical transmission and field enhancement. In addition, we investigate the resonant phenomenon and field enhancement in various configurations. These include scattering with normal and oblique incident waves, TE and TM polarizations, and nanostructures with varying metal film thicknesses and gap sizes. If the gold film is approximately viewed as perfectly electrical conductor, the underlying structure becomes a coaxial waveguide [19]. We model the gold film as a dispersive and lossy material. In the numerical simulation, we also push the gap size to the limit of 1 nm in order to gain strongly localized wave field. This regime was not extensively explored previously, but with recent advances in nanofabrication, it is

now possible to make THz-resonant gaps that are as narrow as 1 nm [7, 8].

The numerical modeling of scattering problem requires solving the full three-dimensional Maxwell's equations in a multi-scale medium, which is challenging due to the smallness of the gap size. Especially, there is extreme scale difference between the wavelength and the gap size. The former ranges from a few hundred microns to a few millimeters in the terahertz regime, whereas the latter has only a few nanometers. Standard numerical approaches such as the finite-difference time-domain (FDTD) method and the finite element method (FEM) would require huge computational resources, since it is necessary to impose tiny grid size in order to resolve the wave fields inside the narrow gap. Here we employ an efficient vertical mode expansion method (VMEM) to analyze the electromagnetic field for the annular gap structure. The VMEM method was recently developed in [20–22] and has also been applied to analyze the electromagnetic field for the bull's eye structures [23]. In contrast to the usual mode matching method, the VMEM method divides the geometry of the problem into several regions which are infinite along the vertical z direction. By expanding the wave field in each region and matching the tangential field components on the boundaries of these regions, a small linear system associated with the expansion coefficients is solved. The method is well suited for problems with a continuous rotational symmetry such as the annular gap considered here.

The rest of the paper is organized as follows. We introduce the geometry of the nanostructure and formulate the scattering problem in Section 2. In Section 3, we outline the vertical mode expansion method for solving the scattering problem. Various numerical results are presented in Section 4 to investigate the resonant phenomenon and the field enhancement in the nanogap. We end the paper by some concluding remarks in Section 5.

2. PROBLEM FORMULATION

A thin gold film with a thickness of d is deposited on the glass substrate and extends to infinity on the xy -plane. A coaxial waveguide is then perforated in the gold film such that it forms an annular gap on the xy plane and is invariant along the z direction (see Figure 1). For simplicity of modeling, we assume that the substrate is semi-infinite and occupies the domain

$$D_+ := \{(x, y, z) \mid z > d\}.$$

The gold film occupies the domain

$$D_d := \{(x, y, z) \mid 0 < z < d\}.$$

Denote the outer and inner radius of the annulus aperture by R_1 and R_0 respectively, then the gap width $w = R_1 - R_0$. The coaxial waveguide is a cylinder given by

$$D_w := \{(x, y, z) \mid (x, y) \in B_{R_1} \setminus B_{R_0}, 0 < z < d\},$$

where B_{R_0} and B_{R_1} are discs with radius of R_0 and R_1 respectively. We consider the gap size w in the nanometer regime so as to maximize the enhancement of the wave field when it passes through the gap. The fabrication technique employed to produce such a tiny gap, called atomic layer lithography, fills the gap with a metal oxide film such as alumina [8, 12, 14, 24].

We assume that the material is nonmagnetic by setting the magnetic permeability $\mu = \mu_0$, wherein μ_0 is the magnetic permeability of the vacuum. The relative permittivity of the gold

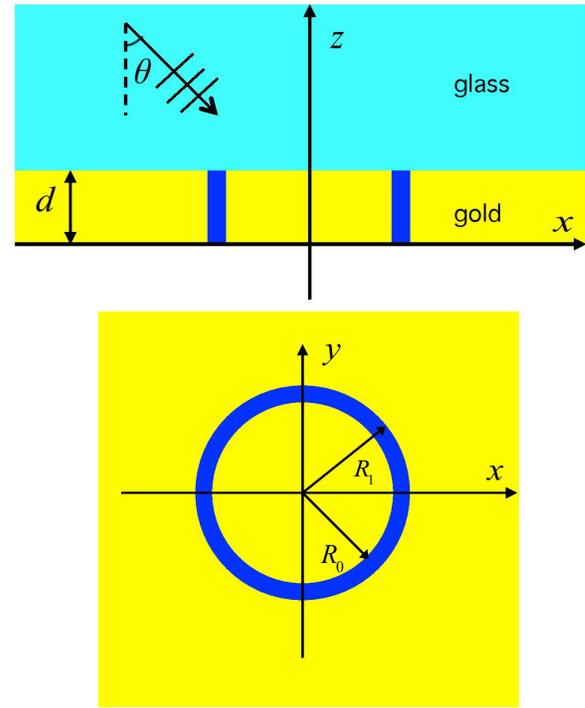


Fig. 1. Side view (top) and top view (bottom) of the nanostructure. The size of the annular gap $w = R_1 - R_0$.

film is evaluated by the Drude model (cf [25]) such that

$$\epsilon_r(\omega) = 1 - \frac{\omega_p^2}{\omega(\omega + i\gamma)}.$$

Here the plasma frequency $\omega_p = 1.37 \times 10^4$ Tera-Radian/s and $\gamma = 40.7$ Tera-Radian/s. The refractive indices of the glass substrate and the alumina that fills the annular nanogap, are set as $n_{SiO_2} = 1.95$ and $n_{Al_2O_3} = 2.12$, respectively [26]. Thus the relative permittivity values in the domains D_+ and D_w are $\epsilon_r = 3.80$ and $\epsilon_r = 4.49$ respectively.

Consider a time-harmonic Terahertz (THz) wave $\{\mathbf{E}^i, \mathbf{H}^i\}$ (with $e^{-i\omega t}$ time dependence) that impinges on the metallic nanostructure from the top. In the absence of the annular gap, the incident plane wave gives rise to a reflected wave and a transmitted wave above and below the gold film respectively. With the annular gap, a scattered wave $\{\hat{\mathbf{E}}^s, \hat{\mathbf{H}}^s\}$ is present and it propagates in all directions. The total electrical field $\hat{\mathbf{E}}$ and the magnetic field $\hat{\mathbf{H}}$ after the scattering are governed by the following Maxwell's equations in the frequency domain:

$$\nabla \times \hat{\mathbf{E}} = i\omega\mu\hat{\mathbf{H}}, \quad \nabla \times \hat{\mathbf{H}} = -i\omega\epsilon\hat{\mathbf{E}} \quad \text{in } \mathbb{R}^3.$$

Let us define $\mathbf{E} = \sqrt{\epsilon_0}\hat{\mathbf{E}}$, $\mathbf{H} = \sqrt{\mu_0}\hat{\mathbf{H}}$, and rewrite the Maxwell's equations in terms of relative physical parameters as

$$\nabla \times \mathbf{E} = ik_0\mathbf{H}, \quad \nabla \times \mathbf{H} = -ik_0\epsilon_r\mathbf{E} \quad \text{in } \mathbb{R}^3,$$

where k_0 is the free space wavenumber. In addition, the scattered field $\{\hat{\mathbf{E}}^s, \hat{\mathbf{H}}^s\}$ satisfies the outgoing radiation condition.

3. VERTICAL MODE EXPANSION METHOD

We employ the VMEM method to solve the scattering problem numerically. In contrast to the traditional horizontal mode

matching method, the key idea of the VMEM method is to expand the electromagnetic field in and outside the nanogap along the invariant z direction by the one-dimensional modes, where the expansion coefficients satisfy scalar two-dimensional Helmholtz equations on the xy -plane. The matching of electromagnetic fields is then imposed on vertical boundaries of the regions in and outside the nanogap. The method is well suited for problems with a continuous rotational symmetry and has been applied to the modeling of electromagnetic scattering of various nanostructures, including a circular hole, bull's eye, photonic crystal slabs, etc [20–23]. Here we apply the method to optical scattering by the annular gap, which also attains a rotational symmetry. In what follows we outline the method and refer the reader to [20] for detailed derivations.

First, the whole \mathbb{R}^3 is decomposed into three domains, D_0 , D_1 and D_2 , which are infinite along the vertical z direction as shown in Figure 2. We adopt the cylinder coordinate where $x = r \cos \varphi$ and $y = r \sin \varphi$, then

$$\begin{aligned} D_0 &:= \{(r, \varphi, z) \mid r < R_0, 0 \leq \varphi < 2\pi, -\infty < z < \infty\}, \\ D_1 &:= \{(r, \varphi, z) \mid R_0 < r < R_1, 0 \leq \varphi < 2\pi, -\infty < z < \infty\}, \\ D_2 &:= \{(r, \varphi, z) \mid r > R_1, 0 \leq \varphi < 2\pi, -\infty < z < \infty\}. \end{aligned}$$

The cross sections of the domains D_0 , D_1 and D_2 are denoted by S_0 , S_1 and S_2 , respectively. In each domain D_ℓ , the permittivity $\varepsilon_r^{(\ell)}$ is piecewise constant along the z direction and is invariant on the cross section S_ℓ . As such the electromagnetic field can be written down as the sum of the vertical modes, which are 1D solutions along the z direction.

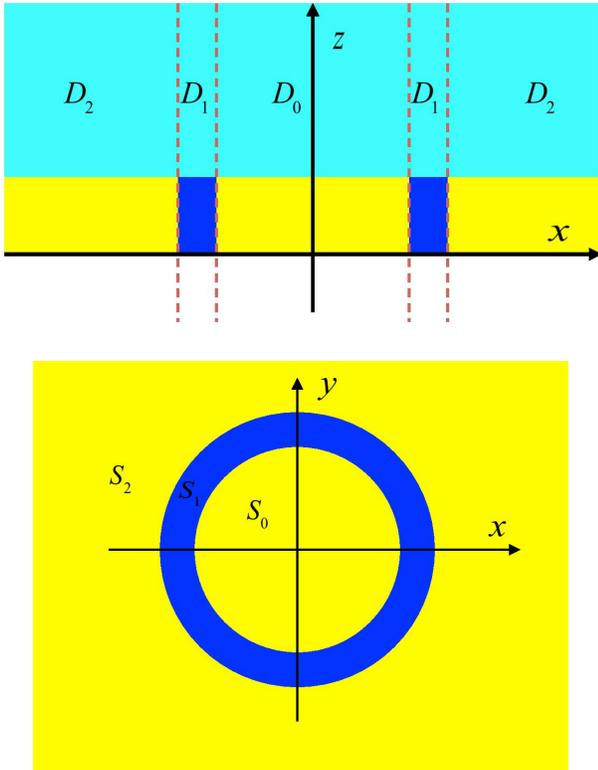


Fig. 2. Side view (top) and top view (bottom) of decomposed domains D_0 , D_1 and D_2 .

For the transverse electric (TE) wave with $E_z^s = 0$ and $H_z^s \neq 0$, the scattered field H_z^s in D_ℓ ($\ell = 0, 1, 2$) can be expressed as

$$H_z^s = \sum_{j=1}^{\infty} [\eta_j^{(\ell,e)}]^2 V_j^{(\ell,e)}(x, y) \phi_j^{(\ell,e)}(z), \quad (1)$$

where $\eta_j^{(\ell,e)}$ and $\phi_j^{(\ell,e)}$ are the eigenvalues and the corresponding eigenfunctions of the following 1D problem:

$$\frac{d^2 \phi_j^{(\ell,e)}}{dz^2} + k_0^2 \varepsilon_r^{(\ell)} \phi_j^{(\ell,e)} = [\eta_j^{(\ell,e)}]^2 \phi_j^{(\ell,e)}, \quad -\infty < z < \infty. \quad (2)$$

Here we use the superscript e to denote the TE wave. Then from the Maxwell's equations, it follows that $V_j^{(\ell,e)}$ satisfies

$$\Delta V_j^{(\ell,e)} + [\eta_j^{(\ell,e)}]^2 V_j^{(\ell,e)} = 0 \quad \text{in } S_\ell, \quad (3)$$

where $\Delta = \partial_x^2 + \partial_y^2$ denotes the Laplace operator. Similarly, for the transverse magnetic (TM) wave with $H_z^s = 0$ and $E_z^s \neq 0$, we express E_z^s in D_ℓ ($\ell = 0, 1, 2$) as

$$E_z^s = \frac{1}{\varepsilon_r^{(\ell)}} \sum_{j=1}^{\infty} [\eta_j^{(\ell,h)}]^2 V_j^{(\ell,h)}(x, y) \phi_j^{(\ell,h)}(z), \quad (4)$$

where $\eta_j^{(\ell,h)}$ and $\phi_j^{(\ell,h)}$ are the eigenvalues and eigenfunctions of the 1D problem

$$\varepsilon_r^{(\ell)} \frac{d}{dz} \left(\frac{1}{\varepsilon_r^{(\ell)}} \frac{d\phi_j^{(\ell,h)}}{dz} \right) + k_0^2 \varepsilon_r^{(\ell)} \phi_j^{(\ell,h)} = [\eta_j^{(\ell,h)}]^2 \phi_j^{(\ell,h)}, \quad -\infty < z < \infty, \quad (5)$$

and $V_j^{(\ell,h)}$ satisfies

$$\Delta V_j^{(\ell,h)} + [\eta_j^{(\ell,h)}]^2 V_j^{(\ell,h)} = 0 \quad \text{in } S_\ell. \quad (6)$$

To obtain the eigenvalues and eigenfunctions $\eta_j^{(\ell,p)}$ and $\phi_j^{(\ell,p)}$ ($p = e, h$), the infinite domain of the 1D problems Eq. (2) and Eq. (5) is truncated to a finite interval (z_b, z_t) . The perfectly matched layers (PMLs) are applied near the two endpoints with zero Dirichlet boundary conditions [27]. Using the rotational symmetry of the problem, the solution $V_j^{(\ell,p)}$ ($p = e, h$) can be expressed as the sum of Bessel functions. More precisely,

$$V_j^{(0,p)} = \sum_{m=-\infty}^{\infty} b_{j,m}^{(0,p)} \frac{J_m(\eta_j^{(0,p)} r)}{J_m(\eta_j^{(0,p)} R_0)} e^{im\varphi} \quad \text{in } S_0, \quad (7)$$

$$\begin{aligned} V_j^{(1,p)} = \sum_{m=-\infty}^{\infty} \left[a_{j,m}^{(1,p)} \frac{H_m^{(1)}(\eta_j^{(1,p)} r)}{H_m^{(1)}(\eta_j^{(1,p)} R_0)} \right. \\ \left. + b_{j,m}^{(1,p)} \frac{H_m^{(2)}(\eta_j^{(1,p)} r)}{H_m^{(2)}(\eta_j^{(1,p)} R_1)} \right] e^{im\varphi} \quad \text{in } S_1, \quad (8) \end{aligned}$$

$$V_j^{(2,p)} = \sum_{m=-\infty}^{\infty} a_{j,m}^{(2,p)} \frac{H_m^{(1)}(\eta_j^{(2,p)} r)}{H_m^{(1)}(\eta_j^{(2,p)} R_1)} e^{im\varphi} \quad \text{in } S_2. \quad (9)$$

Here J_m is the m th order Bessel function of the first kind, $H_m^{(1)}$ and $H_m^{(2)}$ are the m th order Hankel functions of first and second kinds.

Let $\{\mathbf{E}^{(\ell)}, \mathbf{H}^{(\ell)}\}$ be the total field associated with the layered medium for the incident wave $\{\mathbf{E}^i, \mathbf{H}^i\}$, where the permittivity $\varepsilon_r(z) = \varepsilon_r^{(\ell)}(z)$. In light of Eq. (1) and Eq. (4), it follows that, in each region, the total field with the annular gap is given by

$$H_z = H_z^{(\ell)} + \sum_{j=1}^{\infty} [\eta_j^{(\ell,e)}]^2 V_j^{(\ell,e)} \phi_j^{(\ell,e)}, \quad (10)$$

$$E_z = E_z^{(\ell)} + \frac{1}{\varepsilon_r^{(\ell)}} \sum_{j=1}^{\infty} [\eta_j^{(\ell,h)}]^2 V_j^{(\ell,h)} \phi_j^{(\ell,h)}, \quad (11)$$

$$H_\tau = H_\tau^{(\ell)} + \sum_{j=1}^{\infty} \frac{\partial V_j^{(\ell,e)}}{\partial \tau} \frac{d\phi_j^{(\ell,e)}}{dz} + ik_0 \sum_{j=1}^{\infty} \frac{\partial V_j^{(\ell,h)}}{\partial \nu} \phi_j^{(\ell,h)}, \quad (12)$$

$$E_\tau = E_\tau^{(\ell)} + \frac{1}{\varepsilon_r^{(\ell)}} \sum_{j=1}^{\infty} \frac{\partial V_j^{(\ell,h)}}{\partial \tau} \frac{d\phi_j^{(\ell,h)}}{dz} - ik_0 \sum_{j=1}^{\infty} \frac{\partial V_j^{(\ell,e)}}{\partial \nu} \phi_j^{(\ell,e)}. \quad (13)$$

In the above, $\nu = (\nu_x, \nu_y)$ and $\tau = (-\nu_y, \nu_x)$ denotes the unit outward normal vector and tangential vector respectively along the boundaries ∂D_ℓ , H_τ and E_τ are the tangential components in the τ direction.

By substituting Eq. (7) – Eq. (9) into the expansions Eq. (10) – Eq. (13) and imposing the continuity conditions for the electromagnetic fields over the discrete points z_j ($j = 1, 2, 3, \dots, N$) and for $r = R_0$ and R_1 , we collect the Fourier coefficients for each m and obtain a linear system

$$\mathbf{A}_m \mathbf{x}_m = \mathbf{c}_m. \quad (14)$$

\mathbf{A}_m is a $8N \times 8N$ matrix, and the unknown vector

$$\mathbf{x}_m = \begin{bmatrix} \mathbf{b}_m^{(0,e)} \\ \mathbf{b}_m^{(0,h)} \\ \mathbf{a}_m^{(1,e)} \\ \mathbf{a}_m^{(1,h)} \\ \mathbf{b}_m^{(1,e)} \\ \mathbf{b}_m^{(1,h)} \\ \mathbf{a}_m^{(2,e)} \\ \mathbf{a}_m^{(2,h)} \\ \mathbf{a}_m \end{bmatrix}, \quad \mathbf{a}_m^{(\ell,p)} = \begin{bmatrix} a_{1,m}^{(\ell,p)} \\ a_{2,m}^{(\ell,p)} \\ \vdots \\ a_{N,m}^{(\ell,p)} \end{bmatrix}, \quad \mathbf{b}_m^{(\ell,p)} = \begin{bmatrix} b_{1,m}^{(\ell,p)} \\ b_{2,m}^{(\ell,p)} \\ \vdots \\ b_{N,m}^{(\ell,p)} \end{bmatrix}.$$

The vector \mathbf{c}_m is given by

$$\mathbf{c}_m = \left[\mathbf{c}_m^{(1,1)} \mathbf{c}_m^{(1,2)} \mathbf{c}_m^{(1,3)} \mathbf{c}_m^{(1,4)} \mathbf{c}_m^{(2,1)} \mathbf{c}_m^{(2,2)} \mathbf{c}_m^{(2,3)} \mathbf{c}_m^{(2,4)} \right]^T,$$

where the entries of sub-columns $\mathbf{c}_m^{(1,1)}$ and $\mathbf{c}_m^{(2,1)}$ are the Fourier coefficients of the expansions

$$H_z^{(1)}(R_0, \varphi, z_j) - H_z^{(0)}(R_0, \varphi, z_j) = \sum_{m=-\infty}^{\infty} c_{j,m}^{(1,1)} e^{im\varphi},$$

$$H_z^{(2)}(R_1, \varphi, z_j) - H_z^{(1)}(R_1, \varphi, z_j) = \sum_{m=-\infty}^{\infty} c_{j,m}^{(2,1)} e^{im\varphi}.$$

Similarly, the entries of sub-columns $\mathbf{c}_m^{(\ell,2)}$, $\mathbf{c}_m^{(\ell,3)}$ and $\mathbf{c}_m^{(\ell,4)}$ ($\ell = 1, 2$) are defined as the Fourier coefficients of the expansions for $E_z^{(\ell)} - E_z^{(\ell-1)}$, $H_\tau^{(\ell)} - H_\tau^{(\ell-1)}$, and $E_\tau^{(\ell)} - E_\tau^{(\ell-1)}$ respectively. By solving the linear system Eq. (14), we obtain all the expansion coefficients for the total electromagnetic field.

4. RESONANCES AND FIELD ENHANCEMENT INSIDE THE NANOGAP

We consider the configuration where the gold film has a thickness $d = 150$ nm, and the inner radius of the annulus $R_0 = 50$ μm . The frequency of the incident wave is in the THz regime so that strong resonance will be observed. We consider both the normal incidence and the oblique incidence, and investigate the enhanced transmission and field enhancement at resonant frequencies for various gap sizes that range from 1 nm to 50 nm.

A. Normal incidence

We consider the normal incident wave and the electric field has only a nonzero x component such that

$$\mathbf{E}^i = \begin{bmatrix} E_x^i \\ 0 \\ 0 \end{bmatrix}.$$

Figure 3 demonstrates the normalized transmission T for various gap sizes that range from 1 nm to 50 nm. Here the normalized transmission T is defined by

$$T = \frac{P^{\text{extra}}}{P^{\text{inc}}}, \quad (15)$$

where P^{extra} is the extra transmitted power and P^{inc} is the power of normal incident wave over the gap aperture. We define the extra transmitted power by

$$P^{\text{extra}} = - \int_{\mathbb{R}^2} (\mathbf{S}_z - \mathbf{S}_z^{(0)}) dx dy$$

for any $z < 0$. In the above, \mathbf{S}_z and $\mathbf{S}_z^{(0)}$ is the z component of the Poynting vector when the gap is present and not, respectively. Notice that P^{extra} is independent of z . In the computation, we reduce the above integral on \mathbb{R}^2 to line integrals on circles with radii R_0 and R_1 .

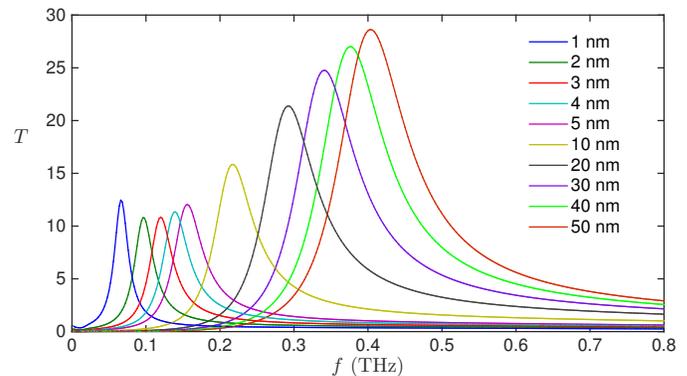


Fig. 3. Normalized transmission T for various frequencies f and different gap sizes w .

First, it is observed that, for a specified gap width w , the transmission T exhibits a peak in the terahertz regime. At the peak, the value of T exceeds 10 for all gap sizes. In particular, T is over 25 at the frequency $f = 0.404$ THz (or at the wavelength $\lambda = 0.743$ nm) when the gap width is 50 nm. That is, the transmission with the annular gap is more than 25 times higher compared to the power incident on the open area of the

gap. Such peak values are related to the Fabry-Perot type resonances that propagate along the length of the coaxial waveguide and is believed to occur near the cutoff frequency for the TE_{11} waveguide mode [14, 15]. To investigate the field enhancement at the resonant frequencies, we consider the gap width $w = 5$ nm and plot $|E_x|$, the magnitude for the x component of the electric field, at the resonant frequency $f = 0.156$ THz in Figures 4 and 5. Both the cross-sectional plots on the xy and xz plane are shown, and it is seen that an enhancement order over 5000 is achieved inside the annular gap for the electric field amplitude. In addition, as observed from Figure 4, the electric field has a $\cos \varphi$ dependence, which also varies the excitation of the TE_{11} mode in the waveguide.

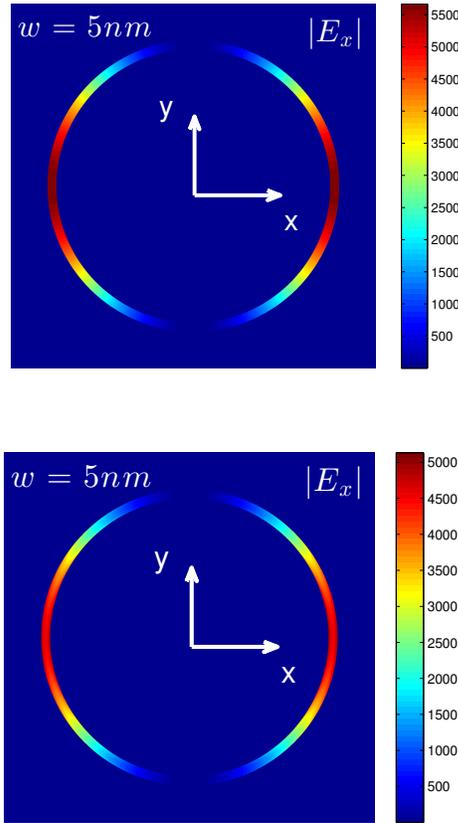


Fig. 4. Cross-sectional plot of $|E_x|$ on the xy plane at the resonant frequency $f = 0.156$ THz: at $z = 75$ nm (top); (b) at $z = 150.4$ nm (bottom). The gap width $w = 5$ nm. The radial variable r is stretched to enlarge the annular gap in the figures.

It is also seen from Figure 3 that the peak of the transmission T (or the resonant frequency) shifts to lower frequencies as the gap size w decreases. Figure 6 plots the resonant frequencies as w increases from 1 nm to 50 nm. A very interesting feature of the resonances for the annular nanogap is the significant shift of the resonant frequency with a tiny change of the gap size. For instance, as w decreases from 5 nm to 1 nm, the resonant frequency shifts from 0.156 THz to 0.06 THz. It is known that the cutoff wavelength of a perfect electrical conducting (PEC) coaxial waveguide made is given by $n_{Al_2O_3} \cdot \pi(R_0 + R_1)$ [15]. Hence the PEC theory is not sufficient to explain the significant shift of the

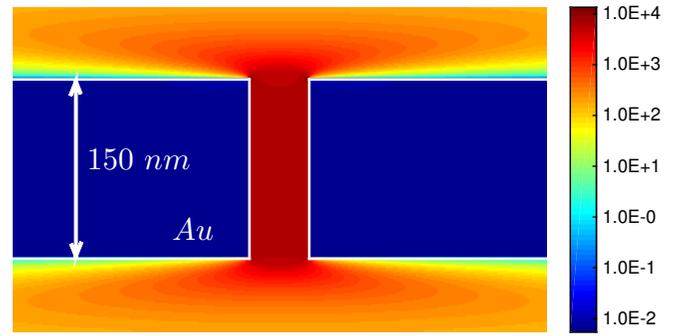


Fig. 5. Cross-sectional plot of $|E_x|$ at the resonant frequency $f = 0.156$ THz on the xz plane when $y = 0$. The gap width $w = 5$ nm.

resonant frequency. On the other hand, it is noted that the cutoff wavelength for the coaxial waveguides made with a real metal differs dramatically from the PEC approximation, especially as the gap size is reduced, and it is believed the cylindrical surface plasmons play an important role in the resonant frequency shift [11, 15].

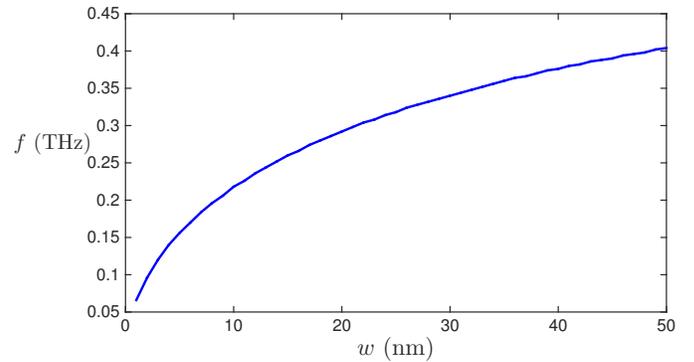


Fig. 6. Resonant frequencies for different gap sizes w . Note that the resonance frequency shifts from 0.156 THz to 0.06 THz as the gap width w decreases from 5 nm to 1 nm.

To demonstrate the enormous field enhancement as the gap size decreases, we calculate the enhancement factor Q at the resonant frequencies, where Q is defined as the ratio between the amplitude of the total field and the incident field given by

$$Q = \frac{|\mathbf{E}|}{|\mathbf{E}^i|}$$

The enhancement factor Q in the middle of the coaxial waveguide, namely at the location $(x, y, z) = (R_0 + w/2, 0, d/2)$, is plotted in Figure 7. We see that the enhancement factor exceeds 10000 if the gap size is sufficiently small. It should be pointed out that the nonlocal electrodynamic effects in such small gaps, which may place an upper bound on the field enhancement, is not taken into account in the physical model considered here [28].

Finally, we calculate the transmission T for several different metal film thicknesses when gap width $w = 5$ nm and plot T values in Figure 8. It is observed that the resonant frequency only

shifts slightly as the thickness d increases from 150 nm to 300 nm. This may be due to the fact that the resonant wavelength of the FP0 mode in the coaxial waveguide is mostly determined by its cutoff frequency and has a propagation constant not heavily dependent on the length of the waveguide [14, 29]. Furthermore, we see that the transmission T increases with a decreasing thickness d .

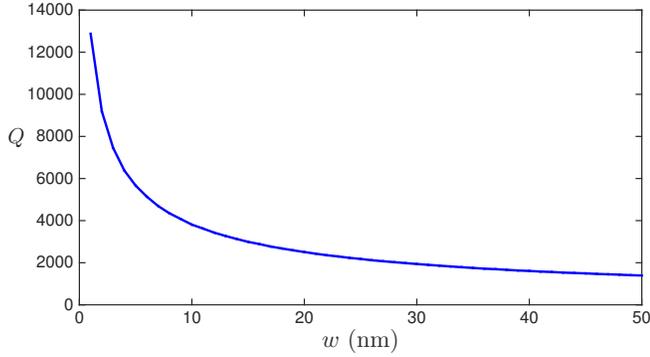


Fig. 7. Enhancement factor Q evaluated at the location $(x, y, z) = (R_0 + w/2, 0, d/2)$ for different gap sizes w .

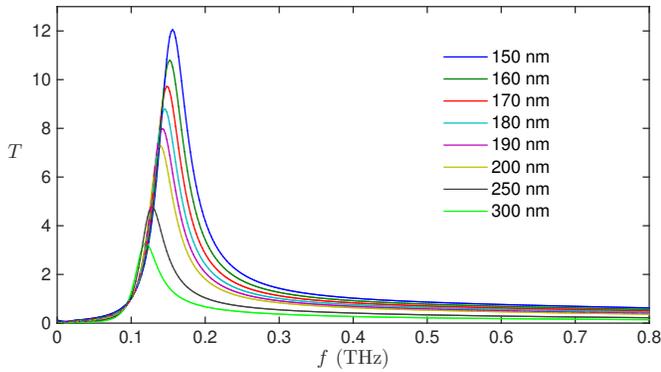


Fig. 8. Normalized transmission T for various frequencies f and different metal thicknesses d . The gap width $w = 5$ nm.

B. Oblique incidence

Let us assume that the incident wave vector is in the xz plane and it forms an angle of θ with the z axis as shown in Figure 1. The geometrical parameters of the nanostructure is the same as the ones in the Section A. We first consider the TM polarization, where

$$\mathbf{E}^i = \begin{bmatrix} E_x^i \\ 0 \\ E_z^i \end{bmatrix}, \quad \mathbf{H}^i = \begin{bmatrix} 0 \\ H_y^i \\ 0 \end{bmatrix}.$$

For the incident angle $\theta = 15^\circ$, the normalized transmission T with various gap sizes is shown in Figure 9. As before, here T is defined as

$$T = \frac{P_{\text{extra}}}{P_{\text{inc}}}, \quad (16)$$

where P_{extra} is the extra transmitted power and P_{inc} is the power of normal incident wave on the gap aperture. We keep the

denominator P_{inc} independent of the incident angle for the convenience of comparison among different incident angles. Correspondingly, the resonant frequencies for w varying from 1 nm to 50 nm are plotted in Figure 10. We see that resonant frequencies of the oblique incidence are indistinguishable from those of normal incidence as shown in Figure 6. This is consistent with the resonance theory where the resonant frequencies are mainly dependent on the nanostructures, rather than the incident angles.

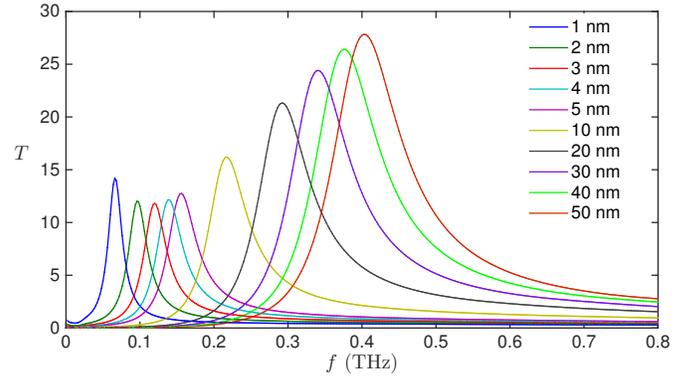


Fig. 9. Normalized transmission T for the TM polarization at various frequencies f and different gap sizes w . The incident angle $\theta = 15^\circ$.

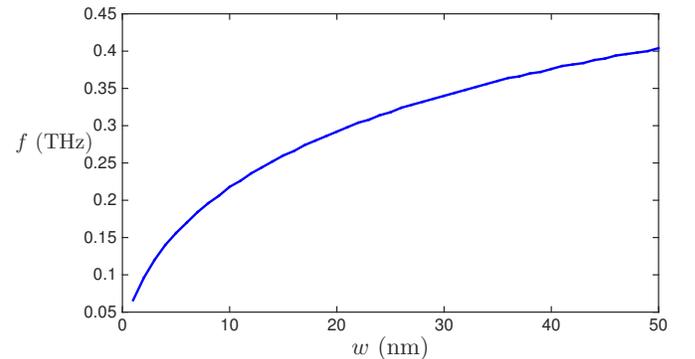


Fig. 10. Resonant frequencies for the TM polarization at different gap sizes w . The incident angle $\theta = 15^\circ$.

To demonstrate the field enhancement in the nanogap, we fixed the incident angle $\theta = 15^\circ$ and vary the gap sizes. The enhancement factor Q at the resonant frequencies and at the location $(x, y, z) = (R_0 + w/2, 0, d/2)$ is plotted for all gap sizes in Figure 11. We see that enhancement factor is only slightly different from the normal incidence case.

Next we consider the TE polarized incident wave, where

$$\mathbf{E}^i = \begin{bmatrix} 0 \\ E_y^i \\ 0 \end{bmatrix}, \quad \mathbf{H}^i = \begin{bmatrix} H_x^i \\ 0 \\ H_z^i \end{bmatrix}.$$

The normalized transmission T at the incident angle $\theta = 15^\circ$ is plotted in Figure 12 for all gap sizes, and the corresponding resonant frequencies are shown in Figure 13. Very interestingly,

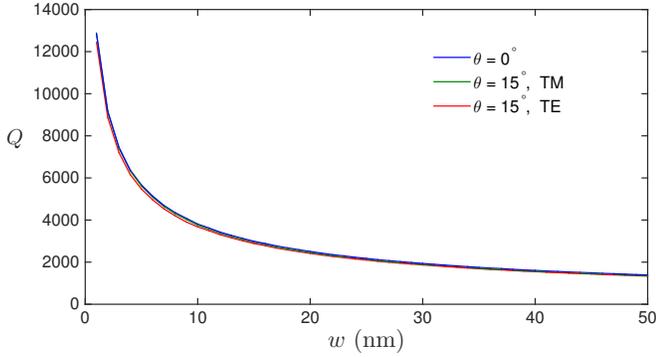


Fig. 11. Enhancement factor Q for different gap sizes w at normal and oblique incident angles. Q is evaluated at the location $(x, y, z) = (R_0 + w/2, 0, d/2)$.

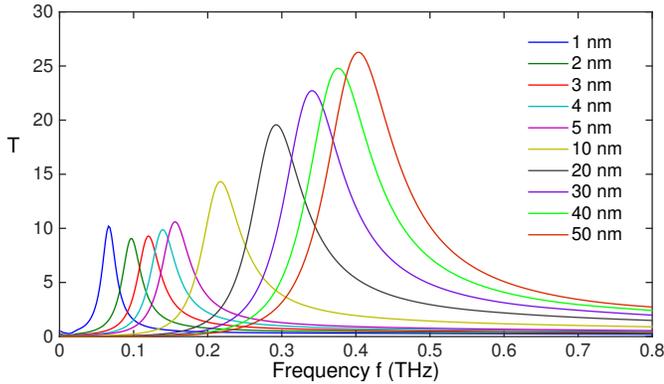


Fig. 12. Normalized transmission T for the TE polarization at various frequencies f and different gap sizes w . The incident angle $\theta = 15^\circ$.

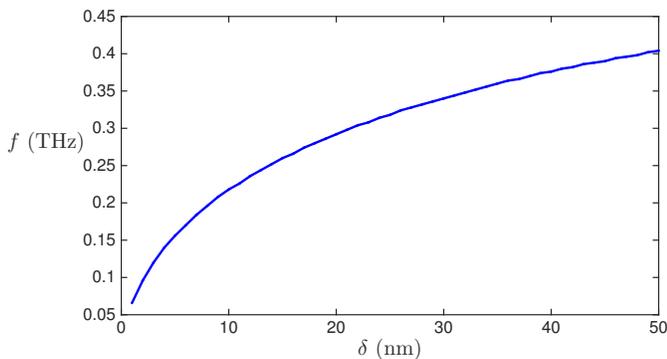


Fig. 13. Resonant frequencies for the TE polarization at different gap sizes w . The incident angle $\theta = 15^\circ$.

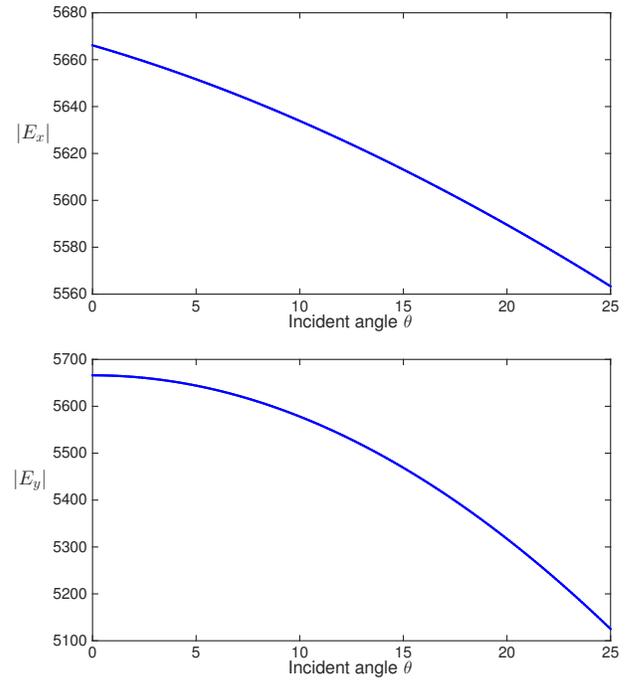


Fig. 14. $|E_x|$ for the TM polarization (top) and $|E_y|$ for the TE polarization (bottom) at the location $(x, y, z) = (R_0 + w/2, 0, d/2)$ at the resonant frequencies for $0 < \theta < 25^\circ$. The gap width $w = 5$ nm.

the coincidence of Figure 12 with Figures 3 and 9 demonstrates the independence of the resonant frequencies on the polarization of the electromagnetic field. For completeness, we also plot the enhancement factor Q at the resonant frequencies and at the location $(x, y, z) = (R_0 + w/2, 0, d/2)$ for all gap sizes in Figure 11. Again, we observe slight differences in the enhancement factor for two polarizations.

Finally, for both the TE and TM polarizations, we vary the incident angles and calculate the corresponding electric field at the location $(x, y, z) = (R_0 + w/2, 0, d/2)$ at the resonant frequencies. The magnitude of the electric field is shown in Figure 14 when the gap width $w = 5$ nm. It is seen that the electric field enhancement varies slowly for $0 < \theta < 25^\circ$.

C. Comparison with the hybrid discontinuous Galerkin method

In this section, we compare the numerical results obtained from the vertical mode expansion method with the simulations for a periodic array of coaxial apertures as presented in [12]. In [12], the field enhancement for an annular nanogap array with a $32 \mu\text{m}$ diameter and a $50 \mu\text{m}$ array periodicity, and perforated in the metal film with a 150 nm thickness is investigated experimentally and numerically. The numerical simulation is carried out by the hybrid discontinuous Galerkin (HDG) method, which is an advanced FEM method, and is more efficient than the FDTD method or the standard FEM for solving Maxwell's equations [30]. The dotted lines in Figure 15 show the calculated field enhancement factor \tilde{Q} for the gap width $w = 2 \text{ nm}$, 5 nm and 10 nm with the HDG method (cf. [12]). Here the field enhancement

factor \tilde{Q} is defined as

$$\tilde{Q} := \int_{S_w} \frac{|E_x|}{|E_x^i|} dx dy = \frac{\int_{S_w} |E_x| dx dy}{|S_w| \cdot |E_x^i|}.$$

S_w denotes one annulus at the interface between the gap and the vacuum and $|S_w|$ denotes its area. From the peaks of the field enhancement, it is inferred that the resonant frequencies for three gap sizes are about 0.375 THz, 0.491 THz, and 0.634 THz, respectively.

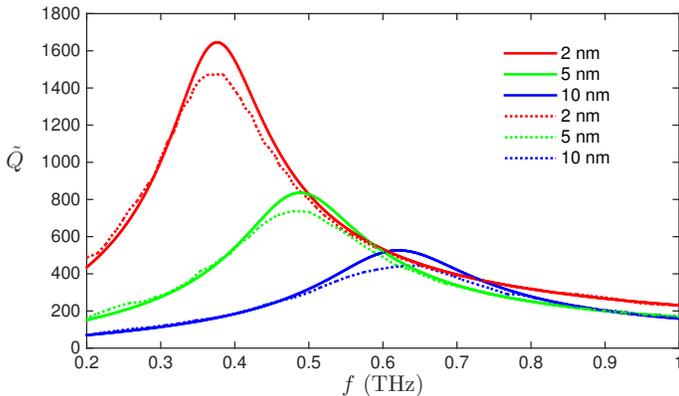


Fig. 15. The field enhancement factor \tilde{Q} obtained by the VMEM method for a single annular gap (solid lines) and by the HDG method for a periodic array of annular gaps (dotted lines).

We apply the VMEM method to simulate the nanostructure with only a single annular gap perforated in the metal film of the same thickness. The diameter of the inner radius is also set as $32 \mu\text{m}$. The refractive index of the aluminum is set as 1.73, 2.12 and 2.35 when the gap width $w = 2 \text{ nm}$, 5 nm and 10 nm , respectively [31]. The calculated field enhancement factor \tilde{Q} is shown in Figure 15 (solid lines), and the resonant frequencies for three gap sizes are about 0.376 THz, 0.488 THz, and 0.621 THz, respectively.

We observe that the resonant frequencies obtained for the single gap are very close to the ones obtained for the periodic case, though there exhibit discrepancies in the magnitude of the field enhancement for the two structures. Such deviation may arise from the different nanostructures under consideration. In particular, it should be noted that the scattered field decays in the far-field zone for the single gap structure, while the scattered field for the periodic structure does not decay. In terms of computational complexity, the VMEM method applied here is an inexpensive scheme that involves the solution of the linear system Eq. (14), whereas the HDG method requires decomposing the computational domain with a 3D mesh and solving the linear system obtained from the Galerkin discretization. For instance, when the gap width is 10 nm , the degree of freedom for the VMEM method is only 2672, while the degree of freedom for the HDG method is over 1 million. Note that the FDTD and the standard FEM methods are even more expensive than the HDG method.

5. CONCLUSION

We investigated numerically the extraordinary optical transmission and field enhancement for an annular nanogap perforated

in the gold film. Especially, we studied how the resonant frequency, the optical transmission and the field enhancement depend on the geometric parameters of the gap, the incident angle and the polarization of the incident wave. The numerical studies provide useful guidance in developing more accurate theoretical models for the scattering problem. It is also useful in providing guidance for the experimental design of nanostructures for specific applications. The VMEM method employed here is very efficient for solving scattering problems with extreme scale difference between the wavelength and the width of the nanogap, which are extremely challenging to solve with conventional FDTD or FEM tools. In particular, it is capable of dealing with the nanostructure with single-digit-nanometer gaps in the terahertz regime without resorting to too many computational resources.

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